Signetics

NE/SA/SE5521
LVDT Signal Conditioner

Product Specification

Linear Products

DESCRIPTION

The NE/SA/SE5521 is a signal conditioning circuit for use with Linear Variable Differential Transformers (LDVTs) and Rotary Variable Differential Transformers (RVDTs). The chip includes a low distortion, amplitude-stable sine wave oscillator with programmable frequency to drive the primary of the LVDT/RVDT, a synchronous demodulator to convert the LVDT/RVDT output amplitude and phase to position information, and an output amplifier to provide amplification and filtering of the demodulated signal.

FEATURES

- **Low distortion**
- **Single supply 5V to 20V, or dual supply ±2.5V to ±10V**
- **Oscillator frequency 1kHz to 20kHz**
- **Capable of ratiometric operation**
- **Low power consumption (182mV typ)**

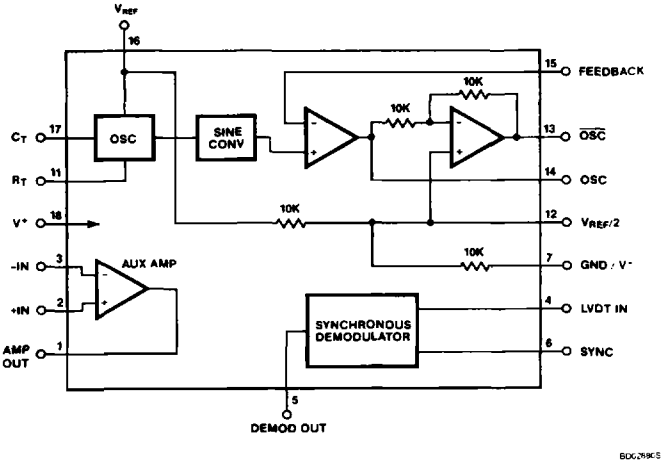
APPLICATIONS

- **LVDT signal conditioning**
- **RVDT signal conditioning**
- **LPDT signal conditioning**
- **Bridge circuits**

ORDERING INFORMATION

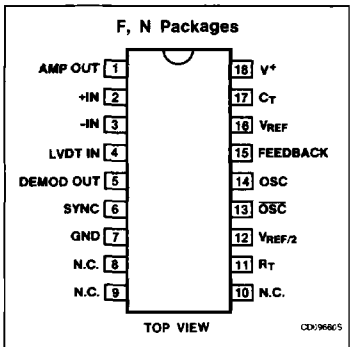
DESCRIPTION	TEMPERATURE RANGE	ORDER CODE
18-Pin Plastic DIP	0 to +70°C	NE5521N
18-Pin Cerdip	0 to +70°C	NE5521F
16-Pin SOL Package	0 to +70°C	NE5521D
18-Pin Plastic DIP	−40°C to +85°C	SA5521N
18-Pin Cerdip	−55°C to +125°C	SE5521F
16-Pin SOL Package	−40°C to +85°C	SA5521D

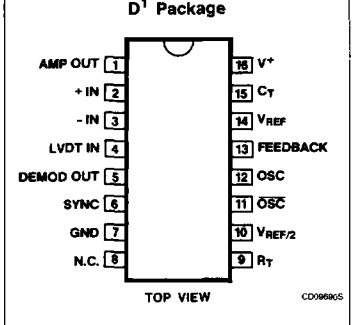
BLOCK DIAGRAM



NOTE:
Pin numbers are for F, N packages

PIN CONFIGURATIONS





NOTE:
1. SOL — released in large SO package only.

PIN DEFINITIONS FOR D, F AND N PACKAGES

PIN NO.		SYMBOL	DEFINITION
D	F, N		
1	1	Amp Out	Auxiliary Amplifier Output.
2	2	+IN	Auxiliary Amplifier non-inverting input.
3	3	-IN	Auxiliary Amplifier inverting input.
4	4	LVDT IN	Input to Synchronous Demodulator from the LVDT/RVDT secondary.
5	5	DEMOD OUT	Pulsating DC output from the Synchronous Demodulator output. This voltage should be filtered before use.
6	6	SYNC	Synchronizing input for the Synchronizing Demodulator. This input should be connected to the OSC or $\overline{OSC}$ output. Sync is referenced to $V_{REF}/2$.
7	7	GND	Device return. Should be connected to system ground or to the negative supply.
8	8	NC	No internal connection.
—	9	NC	No internal connection.
—	10	NC	No internal connection.
9	11	R_T	A temperature stable 18kΩ resistor should be connected between this pin and Pin 7.
10	12	$V_{REF}/2$	A high impedance source of one half the potential applied to V_{REF}. The LVDT/RVDT secondary return should be to this point. A bypass capacitor with low impedance at the oscillator frequency should also be connected between this pin and ground.
11	13	$\overline{OSC}$	Oscillator sine wave output that is 180° out of phase with the OSC signal. The LVDT/RVDT primary is usually connected between OSC and $\overline{OSC}$ pins.
12	14	OSC	Oscillator sine wave output. The LVDT/RVDT primaries are usually connected between OSC and $\overline{OSC}$ pins.
13	15	FEEDBACK	Usually connected to the OSC output for unity gain, a resistor between this pin and OSC, and one between this pin and ground can provide for a change in the oscillator output pin amplitudes.
14	16	V_{REF}	Reference voltage input for the oscillator and sine converter. This voltage MUST be stable and must not exceed +V supply voltage.
15	17	C_T	Oscillator frequency-determining capacitor. The capacitor connected between this pin and ground should be a temperature-stable type.
16	18	+V	Positive supply connection.

ABSOLUTE MAXIMUM RATINGS

SYMBOL	PARAMETER	RATING	UNIT
V_{CC}	Supply voltage	+20	V
	Split supply voltage	±10	V
T_A	Operating temperature range		
	NE5521	0 to +70	°C
	SA5521	-40 to +85	°C
	SE5521	-55 to +125	°C
T_{STG}	Storage temperature range	-65 to +150	°C
P_D	Power dissipation[1]	910	mW

NOTE:
1. For derating, see typical power dissipation versus load curves (Figure 1).

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DC ELECTRICAL CHARACTERISTICS $V+ = V_{REF} = 10V$, $T_A = 0$ to 70°C for NE5521, $T_A = -55$ to +125°C for SE5521, $T_A = -40$ to +85°C for SA5521, Frequency = 1kHz, unless otherwise noted.

SYMBOL	PARAMETER	CONDITIONS	NE5521			SA/SE5521			UNIT
			Min	Typ	Max	Min	Typ	Max	
V_{CC}	Supply current			12.9	20		12.9	18	mA
I_{REF}	Reference current			5.3	8		5.3	8	mA
V_{REF}	Reference voltage range		5		V+	5		V+	V
P_D	Power dissipation			182	280		182	260	mW
Oscillator Section									
	Oscillator output	$R_L = 10k\Omega$		$\frac{V_{REF}}{8.8}$			$\frac{V_{REF}}{8.8}$		V_{RMS}
THD	Sine wave distortion	No load		1.5			1.5		%
	Initial amplitude error	$T_A = 25°C$		0.4	±3		0.4	±3	%
	Tempco of amplitude			0.005	0.01		0.005	0.01	%/°C
	Init. accuracy of oscillator freq.	$T_A = 25°C$		±0.9	±5		±0.9	±5	%
	Temperature coeff. of frequency[1]			0.05			0.05		%/°C
	Voltage coeff. of frequency			2.5			3.3		%/ $V(V_{REF})$
	Min OSC ($\overline{OSC}$) Load[2]		300	170		300	170		=0m
Demodulator Section									
ϵ_r	Linearity error	$5V_{P-P}$ input		±0.05	±0.1		±0.05	±0.1	%FS
	Maximum demodulator input			$\frac{V_{REF}}{2}$			$\frac{V_{REF}}{2}$		V_{P-P}
V_{OS}	Demodulator offset voltage			±1.4	±5		±1.4	±5	mV
TCV_{OS}	Demodulator offset voltage drift			5	25		5	25	µV/°C
I_{BIAS}	Demodulator input current		-600	-234		-500	-234		nA
	$V_{R/2}$ accuracy			±0.1	±1		±0.1	±1	%
Auxiliary Output Amplifier									
V_{OS}	Input offset voltage			±0.5	±5		±0.5	±5	mV
I_{BIAS}	Input bias current		-600	-210		-500	-210		nA
I_{OS}	Input offset current			10	50		10	50	nA
A_V	Gain		100	385		100	385		V/mV
SR	Slew rate			1.3			1.3		V/µs
GBW	Unity gain bandwidth product	$A_V = 1$		1.6			1.6		MHz
	Output voltage swing	$R_L = 10k\Omega$	7	8.2		7	8.2		V
	Output short circuit current to ground or to V_{CC}	$T_A = 25°C$		42	100		42	100	mA

NOTES:

1. This is temperature coefficient of frequency for the device only. It is assumed that C_T and R_T are fixed in value and C_T leakage is fixed over the operating temperature range.
2. Minimum load impedance for which distortion is guaranteed to be less than 5%.

DEFINITION OF TERMS

Oscillator Output	RMS value of the AC voltage available at the oscillator output pin. This output is referenced to $V_{REF/2}$ and is a function of V_{REF}.
Sine Wave Distortion	The Total Harmonic Distortion (THD) of the oscillator output with no load. This is not a critical specification in LVDT/RVDT systems. This figure could be 15% or more without affecting system performance.
Initial Amplitude Error	A measure of the interchangeability of NE/SA/SE5521 parts, *not* a characteristic of any one part. It is the degree to which the oscillator output of a number of NE/SA/SE5521 samples will vary from the median of that sample.
Initial Accuracy of Oscillator Frequency	Another measure of the interchangeability of individual NE/SA/SE5521 parts. This is the degree to which the oscillator frequency of a number of NE/SA/SE5521 samples will vary from the median of that sample with a given timing capacitor.
Tempco of Oscillator Amplitude	A measure of how the oscillator amplitude varies with ambient temperature as that temperature deviates from a 25°C ambient.
Tempco of Oscillator Frequency	A measure of how the oscillator frequency varies with ambient temperature as that temperature deviates from a 25°C ambient.
Voltage Coeffecient of Oscillator Frequency	The degree to which the oscillator frequency will vary as the reference voltage (V_{REF}) deviates from +10V.
Min OSC ($\overline{OSC}$) Load	Minimum load impedance for which distortion is guaranteed to be less than 5%.
Linearity Error	The degree to which the DC output of the demodulator/amplifier combination matches a change in the AC signal at the demodulator input. It is measured as the worst case nonlinearity from a straight line drawn between positive and negative fullscale end points.
Maximum Demodulator Input	The maximum signal that can be applied to the demodulator input without exceeding the specified linearity error.

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APPLICATION INFORMATION

$$\text{OSC frequency} = \frac{V_{REF} - 1.3V}{V_{REF}(R_T + 1.5k)C_T}$$

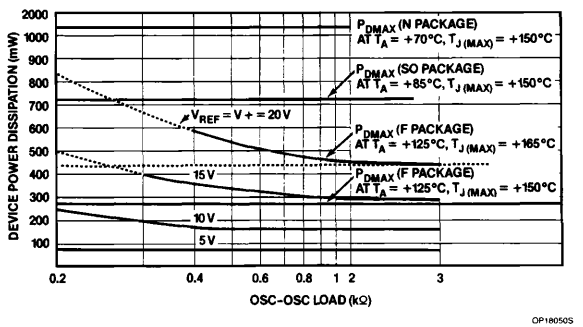

Figure 1. Device Power Dissipation vs OSC - $\overline{OSC}$ Load at +25°C

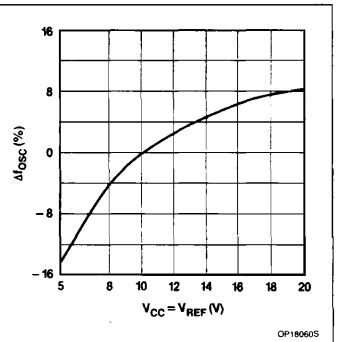

Figure 2. Oscillator Frequency Variation With Voltage (Normalized to $V_{REF} = V_{CC}$=10V) T_A = +25°C

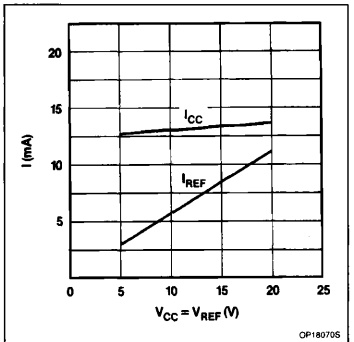

Figure 3. I_{REF} and I_{CC} vs Voltage (T_A = +25°C)

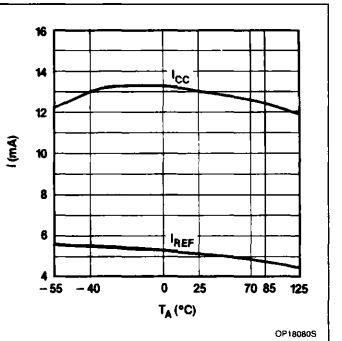

Figure 4. I_{REF} and I_{CC} vs Temperature ($V_{REF} = V_{CC}$ = 10V)